## PHYSICAL INTERPRETATION AND STRENGTHENING OF M. H. PROTTER'S METHOD FOR VIBRATING NONHOMOGENEOUS MEMBRANES; ITS ANALOGUE FOR SCHRÖDINGER'S EQUATION

## JOSEPH HERSCH

The origin of this work lies partly in M. H. Protter's method [7], [8], partly in two papers [3], [5], developing the idea, found in *Payne-Weinberger* [6], of auxiliary one-dimensional problems; the physical interpretation in § 3 rejoins that of [2] and [4].

1. We consider the first eigenvalue  $\lambda_1$  of a nonhomogeneous membrane with specific mass  $\rho(x, y) \ge 0$  covering a plane domain D and elastically supported (elastic coefficient k(s)) along its boundary  $\Gamma$ :

$$arDelta u + \lambda 
ho(x,y) u = 0 ext{ in } D$$
 ,  $rac{\partial u}{\partial n} + k(s) u = 0 ext{ along } \Gamma$  ,

where  $\vec{n}$  is the outward normal.

Every continuous and piecewise smooth function v(x, y) furnishes an upper bound for  $\lambda_1$ : By Rayleigh's principle

$$\lambda_1 = \mathrm{Min}_v rac{D(v) + \oint_F k(s) v^2 ds}{ \iint_D 
ho v^2 dA}$$

where ds is the length element, dA the element of area, and D(v) the Dirichlet integral  $\iint_{D} \operatorname{grad}^2 v \, dA$ . The Minimum is realized if  $v = u_1(x, y)$  (first eigenfunction, satisfying  $\varDelta u_1 + \lambda_1 \rho u_1 = 0$ ).

In the opposite direction, we are here in search of a Maximum principle for  $\lambda_1$ , from which we could calculate lower bounds.

2. Let us consider in D a sufficiently regular vector field  $\vec{p}$  (we shall discuss presently what discontinuities are allowed), satisfying the condition

(1) 
$$ec{p} \cdot ec{n} \leq k(s)$$
 along  $\varGamma$ .  
 $\operatorname{grad}^2 u_1 + (ec{p}^2 - \operatorname{div} ec{p}) u_1^2 = -\operatorname{div} (u_1^2 ec{p}) + \operatorname{grad}^2 u_1 + u_1^2 ec{p}^2 + 2u_1 \operatorname{grad} u_1 \cdot ec{p}$   
 $= -\operatorname{div} (u_1^2 ec{p}) + (\operatorname{grad} u_1 + u_1 ec{p})^2 \geq -\operatorname{div} (u_1^2 ec{p})$ .

Let us integrate this inequality:

Received October 10, 1960. Battelle Memorial Institute, Geneva, and Swiss Federal Institute of Technology, Zürich.